





## **Description**

The J100N50X4B is high performance Aluminum Nitride (AIN) half flange termination intended as a cost competitive alternative to Beryllium Oxide (BeO). The termination is well suited to all cellular frequency bands such as; AMPS, GSM, DCS, PCS, PHS and UMTS. The high power handling makes the part ideal for terminating circulators, and for use in power combiners. The termination is also RoHS compliant!

## **General Specifications**

Resistive Element Thick Film

Substrate AIN Ceramic

Mounting Flange Copper, nickel plated per QC-N-290

Operating Temperature -55°C to +150°C (see de rating chart)

Tolerance is  $\pm 0.010$ ", unless otherwise specified. Designed to meet or exceed applicable portions of MIL-E-5400. All dimensions in inches.

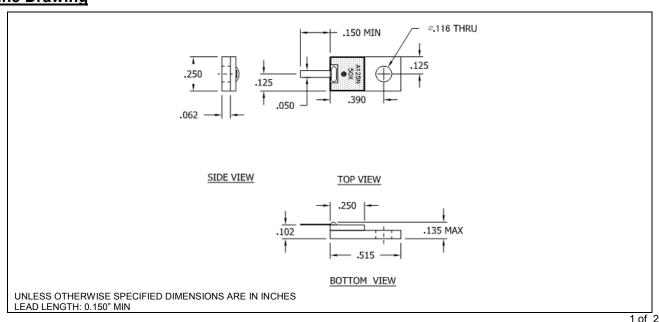
#### **Electrical Specifications**

Specification based on unit properly installed using suggested mounting instructions and a 50 ohm nominal impedance. **Specifications subject to change.** 

#### Features:

- RoHS Compliant
- 100 Watts
- DC 4.0 GHz
- AIN Ceramic
- Non-Nichrome Resistive Element
- Low VSWR
- 100% Tested

## **Outline Drawing**

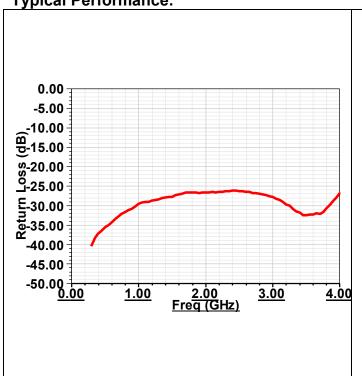


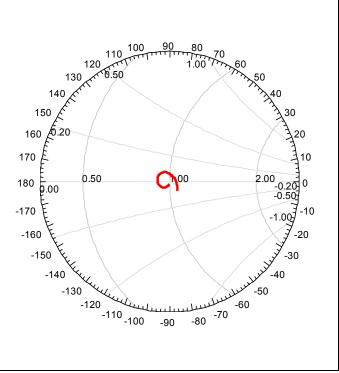


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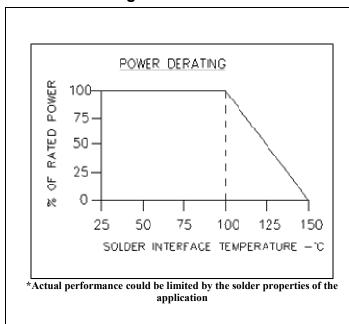


**Typical Performance:** 

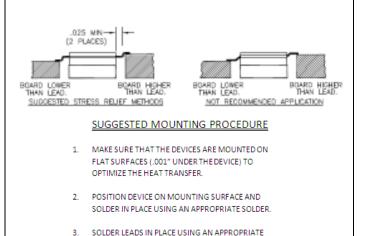




## Power De-rating:



## **Mounting Footprint and Procedure:**



SOLDER TYPE WITH A CONTROLLED TEMPERATURE IRON.

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## Anaren:

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